

MAT01AH

Data Sheet

Trans GP BJT NPN 45V 0.025A 6-Pin TO-78 Tube

Manufacturers Analog Devices, Inc

Package/Case CAN6

Product Type Transistors

RoHS

Lifecycle



Images are for reference only

Please submit RFQ for MAT01AH or Email to us: sales@ovaga.com We will contact you in 12 hours.

RFO

General Description

The MAT01 is a monolithic dual NPN transistor. An exclusive Silicon Nitride "Triple-Passivation" process provides excellent stability of critical parameters over both temperature and time. Matching characteristics include offset voltage of $40\mu V$, temperature drift of $0.15\mu V/^{\circ}C$, and hFE matching of 0.7%.

Very high h is provided over a six decade range of collector current, including an exceptional hFE of 590 at a collector current of only 10nA. The high gain at lower collector current makes the MAT01 ideal for use in low-power, low-level input stages.

Features	Application
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Low VOS (VBE match): 40 µV typical, 100 µV maximum Weigh scales

Low TCVOS: 0.5 μV/°C maximum

Low noise, op amp, front end

High hFE: 500 minimum Current sink/source

Excellent hFE linearity from 10 nA to 10 mA

Low noise instrumentation amplifiers

Low noise voltage:0.23 µV p-p from 0.1 Hz to 10 Hz

Voltage controlled attenuators

High breakdown: 45 V min Log amplifiers



Related Products



MAT04FPZ
Analog Devices, Inc
DIP14



MAT03EH
Analog Devices, Inc
TO78-6



MAT01GHZ
Analog Devices, Inc
TO-78



Analog Devices, Inc TO-78

MAT01GH



MAX5078BATT

Analog Devices, Inc TDFN



MAX20050ATC/V+T

Analog Devices, Inc TDFN-C



MAT14ARZ

Analog Devices, Inc 14-SOIC (0.154, 3.90mm Width)



MAX2602ESA

Analog Devices, Inc 8-SOIC (0.154, 3.90mm Width)